

A detailed circuit diagram of the ESP P3a Class AB Audio Power Amplifier is visible in the background. The schematic includes a multi-stage input section with transistors Q1, Q2, Q3, and Q4, followed by a push-pull output stage with transistors Q5 and Q6. Various resistors (R1 through R8) and capacitors (C1, C2, C3) are used for biasing, frequency response, and coupling. A diode D1 is also present in the input path. The overall layout is symmetrical, typical of Class AB amplifiers.

ESP P3a Class AB Audio Power Amplifier

From Reverse Engineering to High-Fidelity Sound

A personal journey into mastering analog signal amplification

Designed by Rod Elliott, Reverse Engineered by Mukhtar Suleman



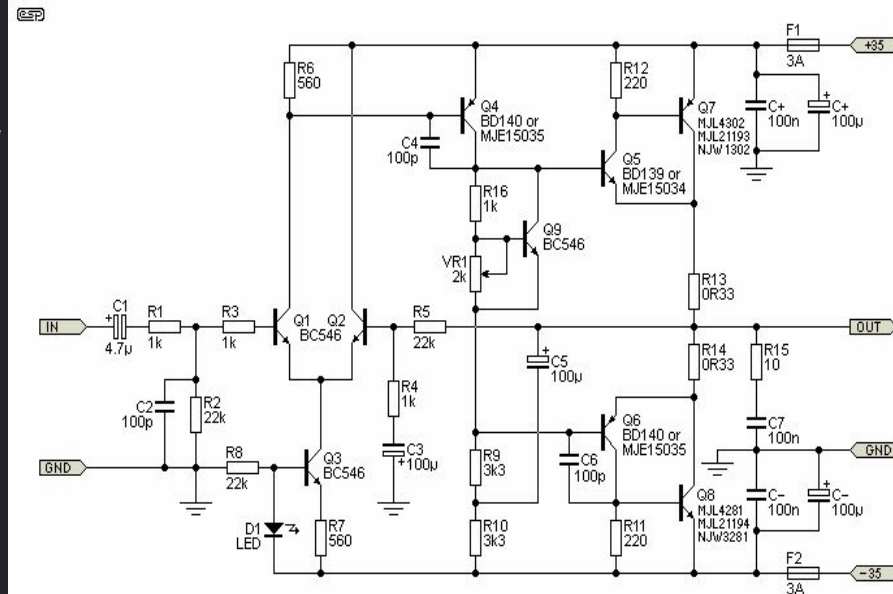
Architecture & Design Choice

The goal was to design and prototype a **100W Class AB audio amplifier** for high-fidelity speaker output — combining **clean sound** with **efficient power delivery**.

After evaluating amplifier topologies:

- **Class A** offers excellent linearity but is highly inefficient (~25%).
- **Class B** improves efficiency (~78%) but suffers from **crossover distortion**.
- **Class AB** strikes a balance — by using **diode or V_{BE} biasing**, both output transistors remain slightly on, reducing distortion and preserving efficiency.

I chose to reverse engineer **Rod Elliott's ESP P3a design** due to its clean schematic layout, thermal stability, and proven high-fidelity performance — making it ideal for hands-on prototyping and learning.



Spec	Target Value
Output Power	100W @ 4Ω
Voltage Rails	±35V
Frequency Response	20Hz–20kHz
THD+N	< 0.1%
Application	Home Stereo Audio

ESP P3A Design Requirements & Specifications

Parameter	Specification
Power Output	60–100 W RMS per channel
Load Impedance	8 Ω (± 42 V rails) or 4 Ω (± 35 V rails)
Supply Voltage (Rails)	± 35 V for 4 Ω loads; ± 42 V for 8 Ω loads
THD+N	< 0.05% at 1 kHz, full power
Frequency Response	10 Hz – 100 kHz (–1 dB)
Slew Rate	20 V/ μ s
Thermal Considerations	Large heatsink required; bias transistor mounted on heatsink for thermal tracking
Stability	Stable with capacitive loads; phase margin > 45°; gain margin > 10 dB
Application	Hi-Fi stereo, bi-amp systems, instrument amplifiers

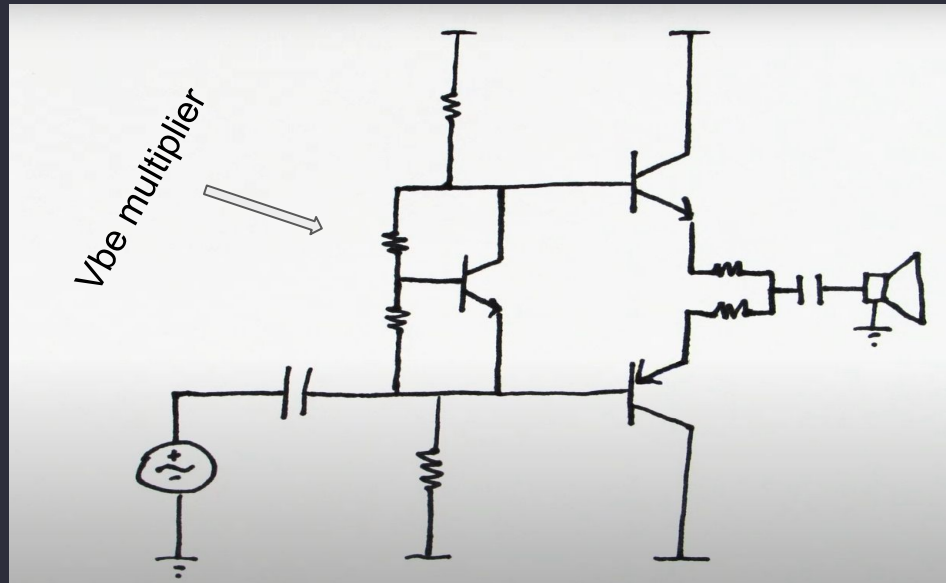
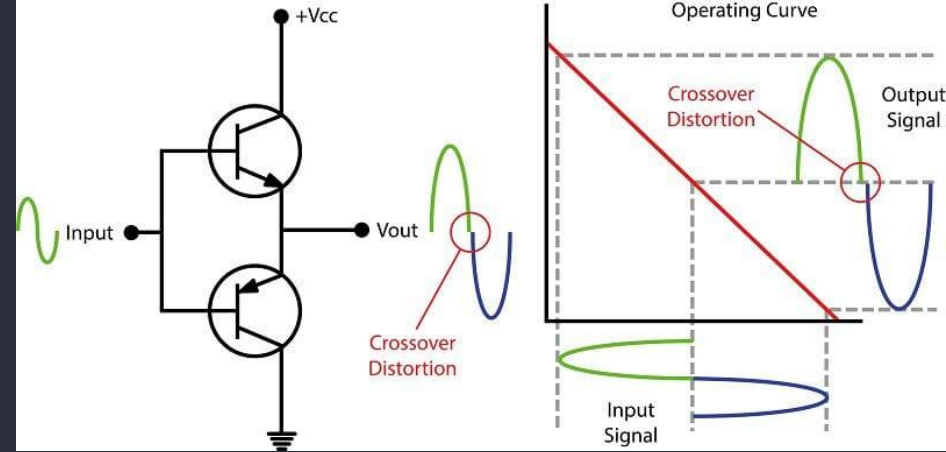
Class AB Topology Explanation

Behavior Summary:

- At $V_{in} = 0V$
 - Both NPN and PNP slightly conduct → no distortion at zero-crossing.
- 1. $V_{in} > 0$ (Positive Half)
 - NPN turns on more → sources current to the load.
 - PNP turns off gradually.
- 2. $V_{in} < 0$ (Negative Half)
 - PNP turns on more → sinks current from the load.
 - NPN turns off gradually.

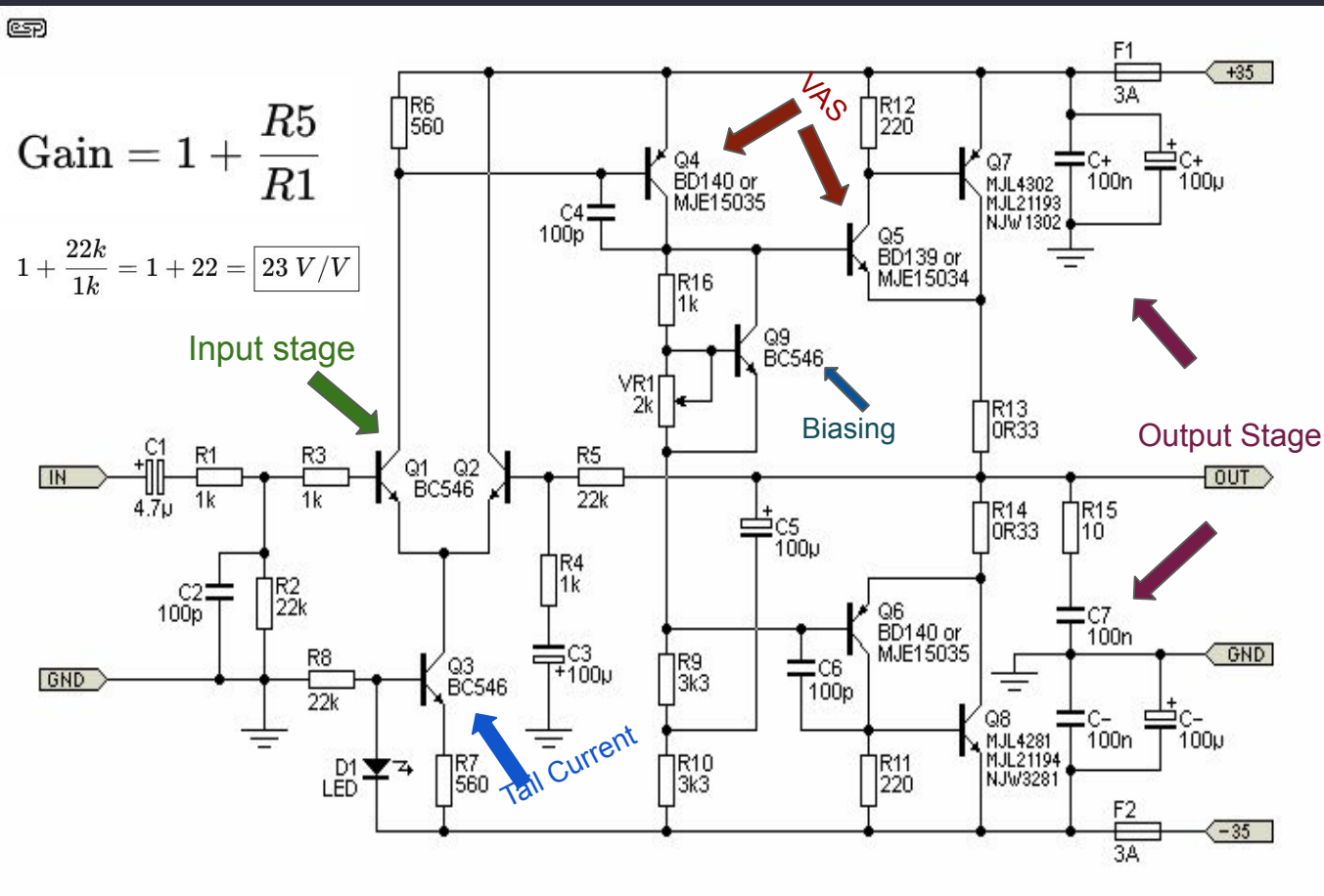
Mitigating Crossover Distortion:

- V_{BE} multiplier creates a modest quiescent current (typically 50–100 mA per output transistor), just enough to avoid distortion without excessive heat.



ESP P3a schematic

Block	Components
Input Stage	Q1, Q2, R1, R2, R3, R4, R5
Tail Current Source	Q3, D1, R7
Voltage Amplification Stage (VAS)	Q4, Q5, R16, C4
Bias Control (V_BE Multiplier)	Q9, VR1, R16
Output Stage (Class AB)	Q6, Q7, Q8, R13, R14, C7
Feedback & Output Filtering	OUT node → R15, C7, trace back to R2



Simulation & Validation Process

I simulated the ESP P3a input stage in LTSpice to validate the differential pair's behavior.

To isolate the stage, I disconnected the feedback loop from Q2's base.

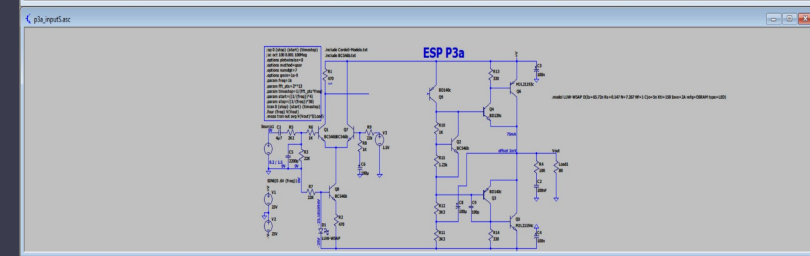
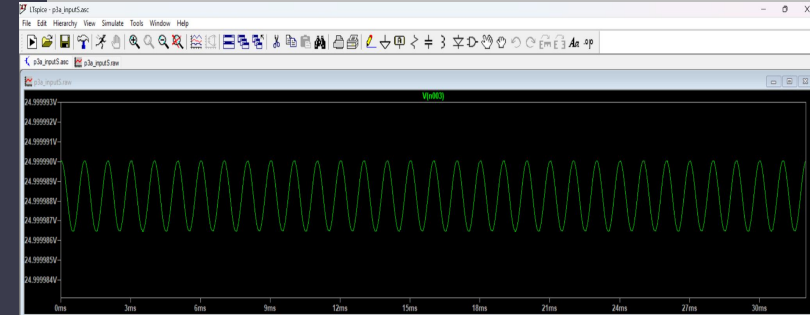
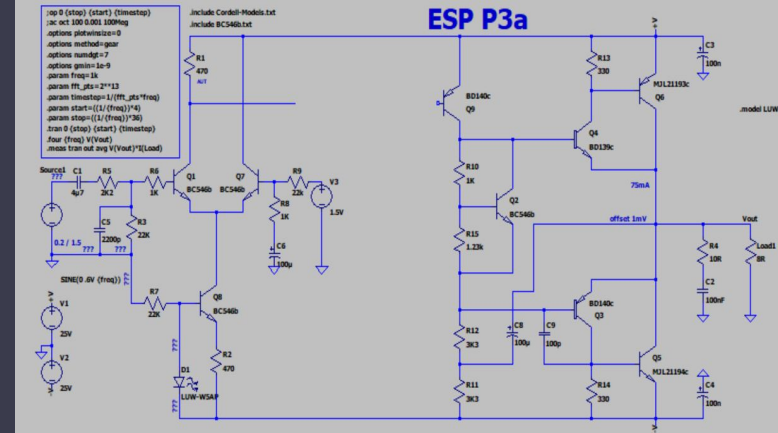
I applied a 1.5V AC signal to Q1's base to mimic an audio input.

The tail current source uses a white LED (3.2V) and BJT with a 470Ω emitter resistor:

- Tail current $\approx (3.2\text{V} - 0.7\text{V}) / 470\Omega \approx 5.3\text{ mA}$
- $\approx 2.65\text{ mA}$ per transistor

Transconductance: $g_m \approx 2.65\text{ mA} / 25\text{ mV} = 0.106\text{ S}$

Voltage gain: $A \approx g_m \times RC = 0.106 \times 470 \approx 49.8\text{ V/V}$ (~34 dB)



Simulation & Validation Process

Voltage gain stage (VAS) and Class AB driver components now added

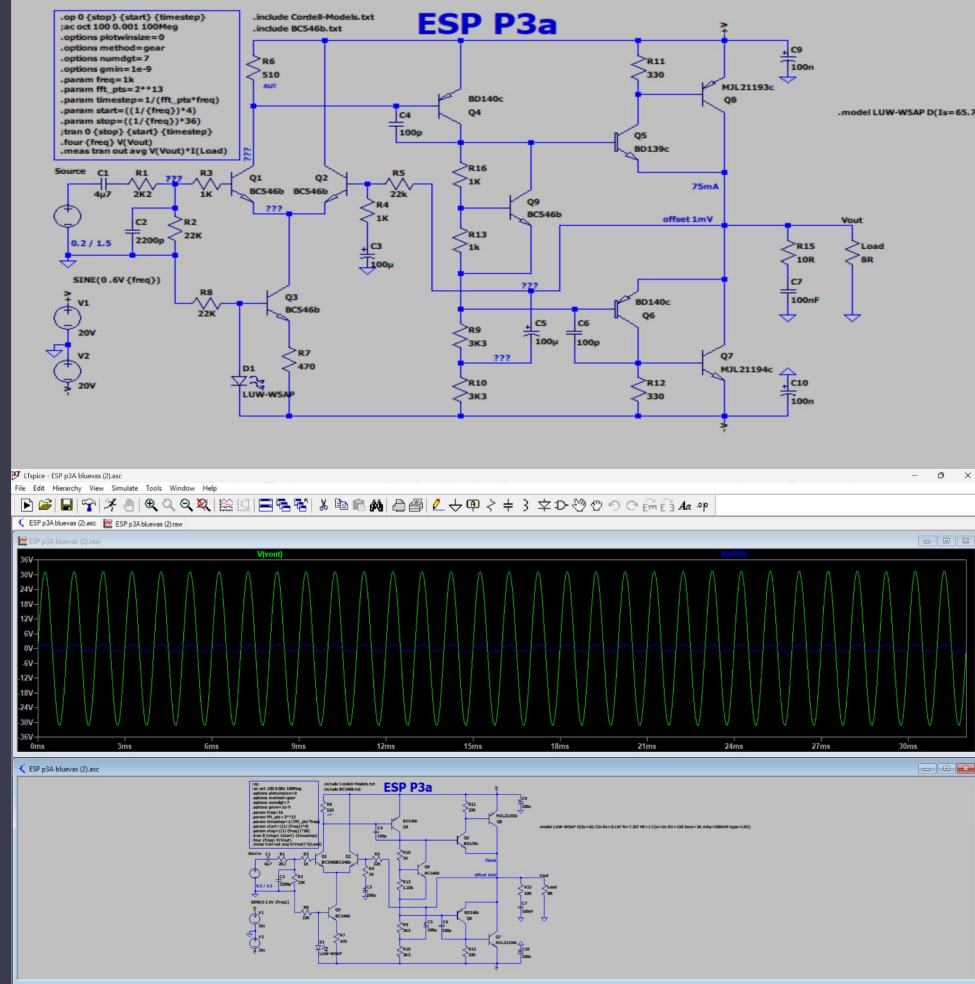
Q4 and Q5 form the core of the gain stage:

- Q4 acts as the current source load.
- Q5 operates as the **voltage amplification stage (VAS)**, boosting the signal from the input stage.

Q5 also drives the PNP transistor (Q8) — the upper half of the Class AB output stage.

The **Class AB output biasing** is controlled by Q9, which is configured as a **VBE multiplier**

- This sets the **quiescent current** between Q8 (PNP) and Q6 (NPN), helping to minimize crossover distortion
- $30\text{Vpp} > 21.2\text{Vrms} > P = (21.2)^2/8 = 56.2\text{W}$ or $P = (21.2)^2/4 = 112.4\text{W}$



Simulation Results (LTSpice)

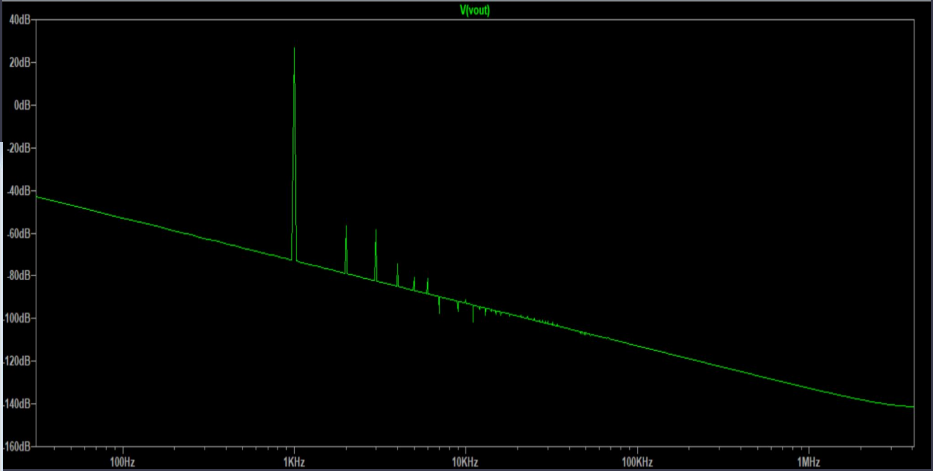
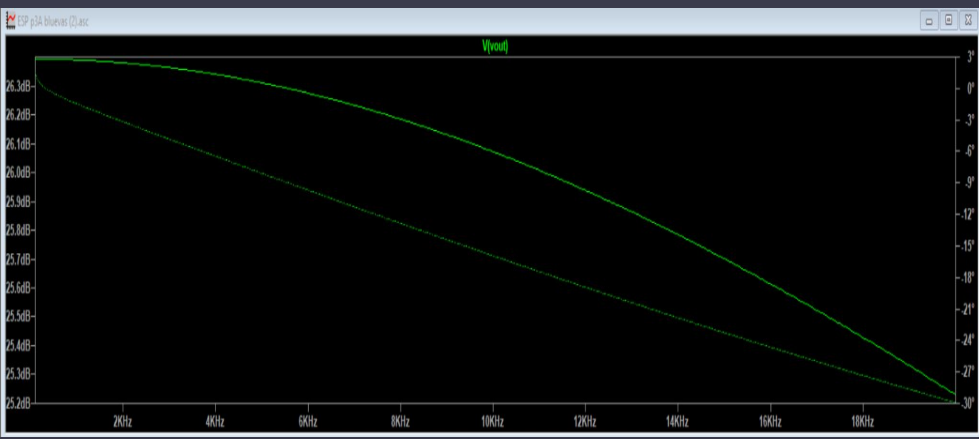
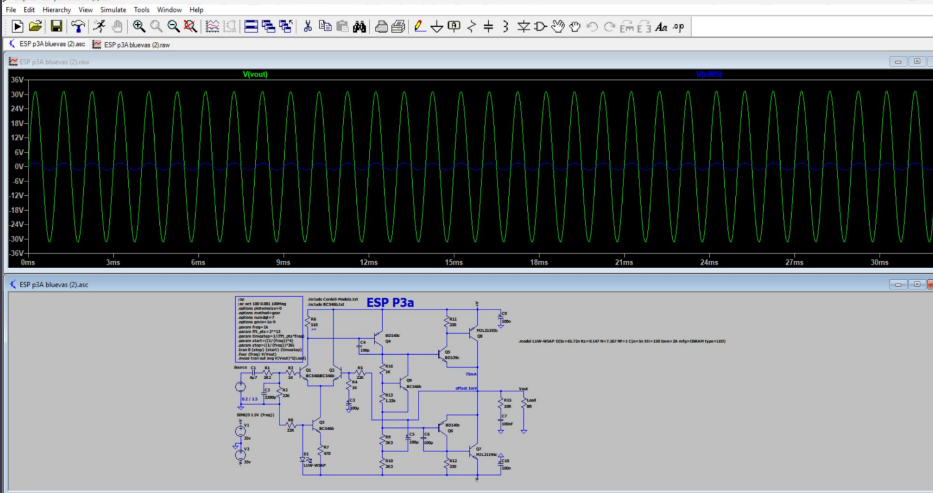
Gain: V_{out} / V_{in}
 $30V / 1.5 = 20$

Direct Newton iteration for .op point succeeded.
N-Period=1
Fourier components of V(vout)
DC component:-0.0572217

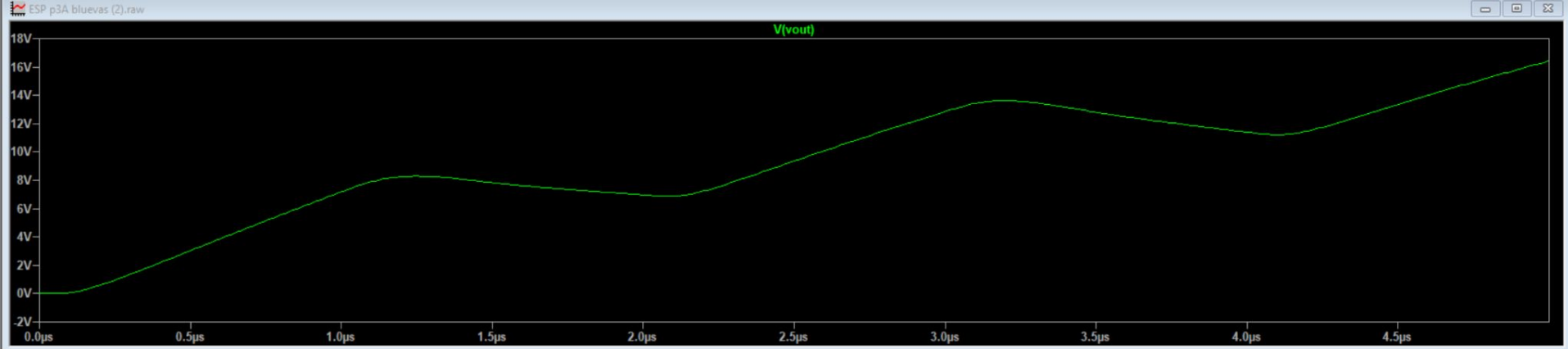
Harmonic Number	Frequency [Hz]	Fourier Component	Normalized Component
1	1.000e+3	3.130e+1	1.000e+0
2	2.000e+3	2.074e-3	6.627e-5
3	3.000e+3	1.728e-3	5.522e-5
4	4.000e+3	2.778e-4	8.876e-6
5	5.000e+3	1.271e-4	4.061e-6
6	6.000e+3	1.122e-4	3.586e-6
7	7.000e+3	2.221e-5	7.098e-7
8	8.000e+3	3.683e-5	1.177e-6
9	9.000e+3	1.813e-5	5.795e-7

Partial Harmonic Distortion: 0.008690%
Total Harmonic Distortion: 0.008694%

↑ THD Frequency response ↓

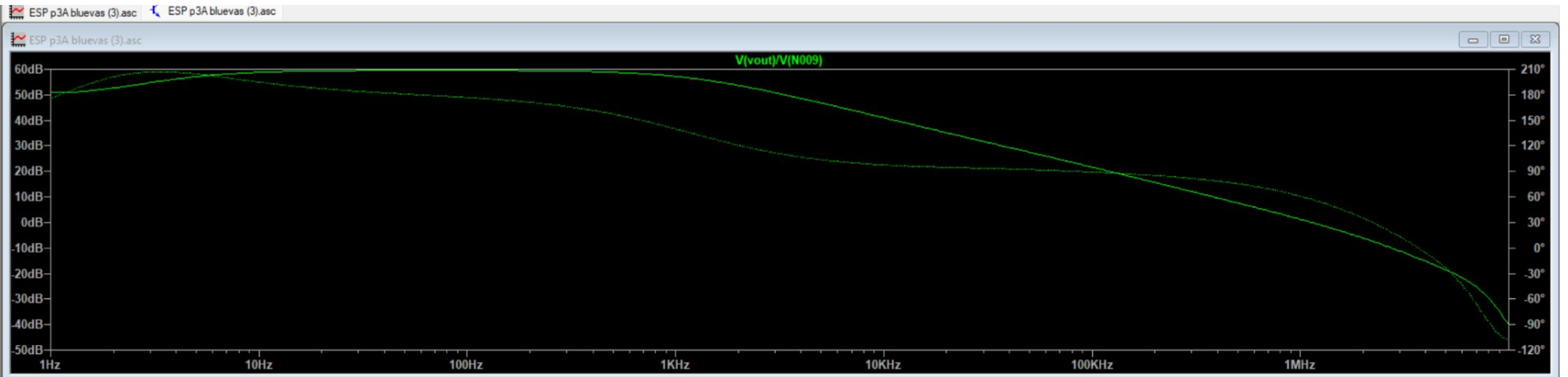


FFT ↑



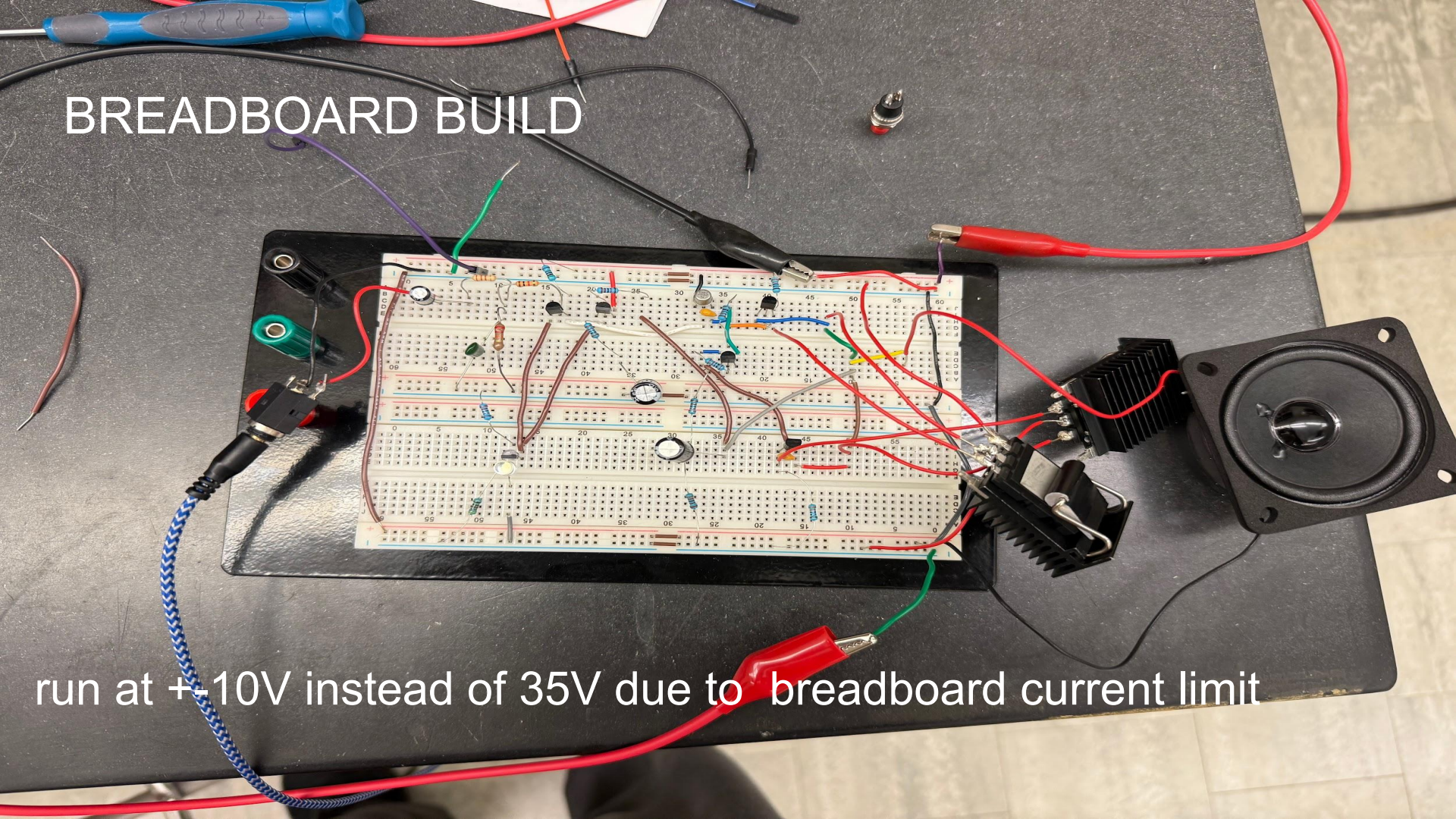
Slew rate = $V/\mu s = 3V/5\mu s = .6V/\mu s$ - pretty low for power audio amplifiers ↗

Unity gain point frequency at 1.13Mhz, 29°



BREADBOARD BUILD

run at $\pm 10V$ instead of 35V due to breadboard current limit



What I could still validate at $\pm 10V$

<u>Test/Observation</u>	<u>What It Confirms</u>
<u>DC operating points</u>	<u>Biasing of all transistors (VAS, differential pair, output)</u>
<u>Quiescent current</u>	<u>V_{BE} multiplier working, output stage not oscillating</u>
<u>Small-signal gain</u>	<u>Expected voltage gain (still close to 20×, scaled output)</u>
<u>Waveform symmetry</u>	<u>Output is centered at 0V, no major offset</u>
<u>Crossover distortion check</u>	<u>Class AB smooth zero-crossing behavior</u>
<u>Stability</u>	<u>No self-oscillation at idle or with input signal</u>

Breadboard Results

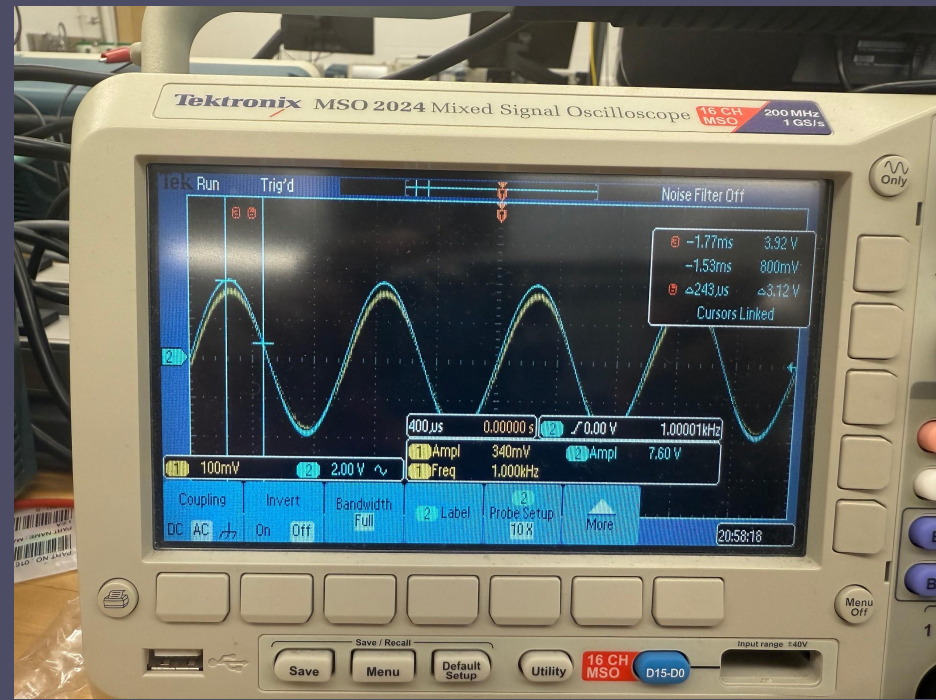
Input signal: sine 350mV 1khz yellow probe

Output: 7.60V blue probe

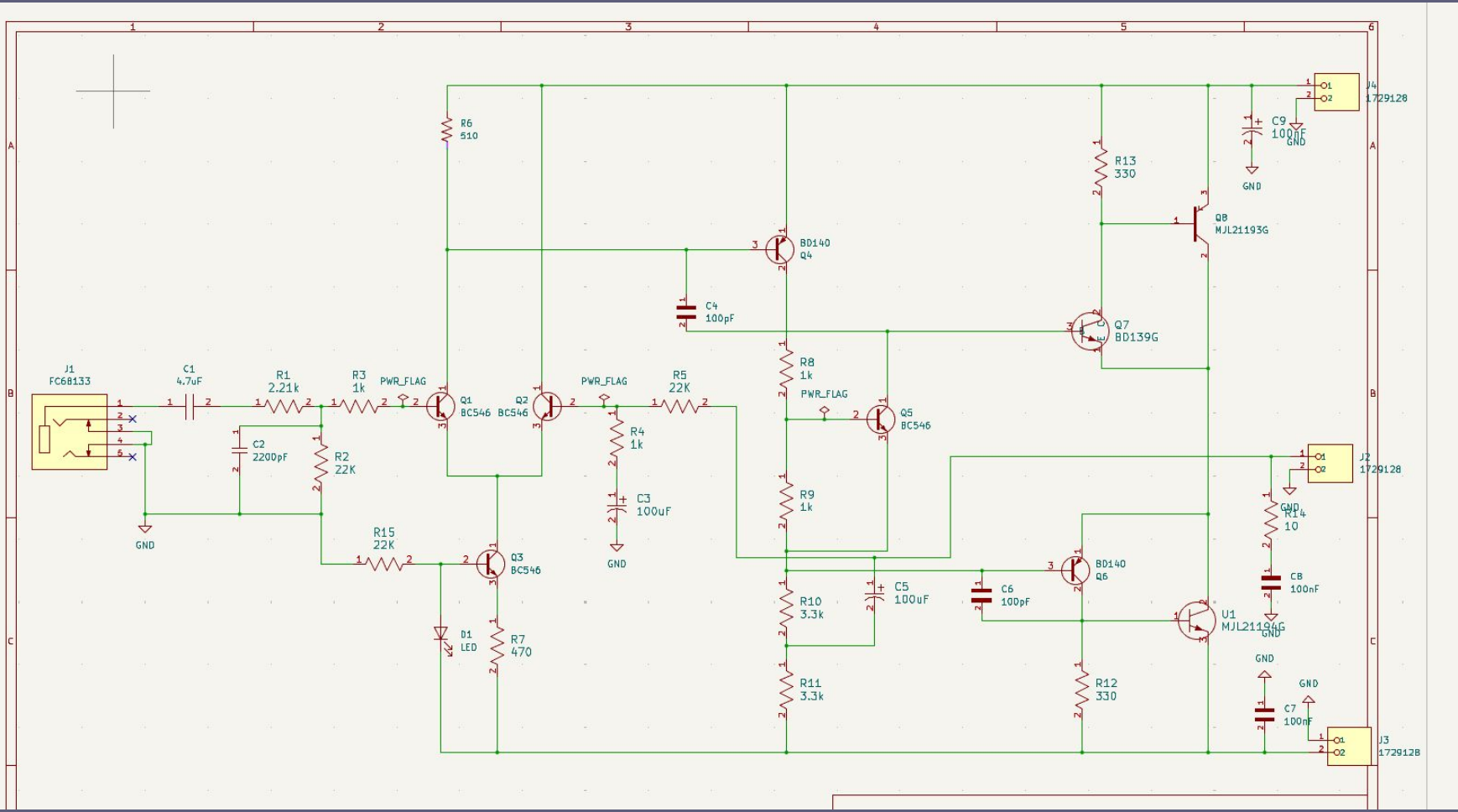
$$\text{Gain} = 7.6 / .35 = 21.7 \text{V/V} \approx 23 \text{V/V}$$

<https://youtube.com/shorts/S-6Zr4V4KZg?si=dZFbJgk70pWXQKoZ>

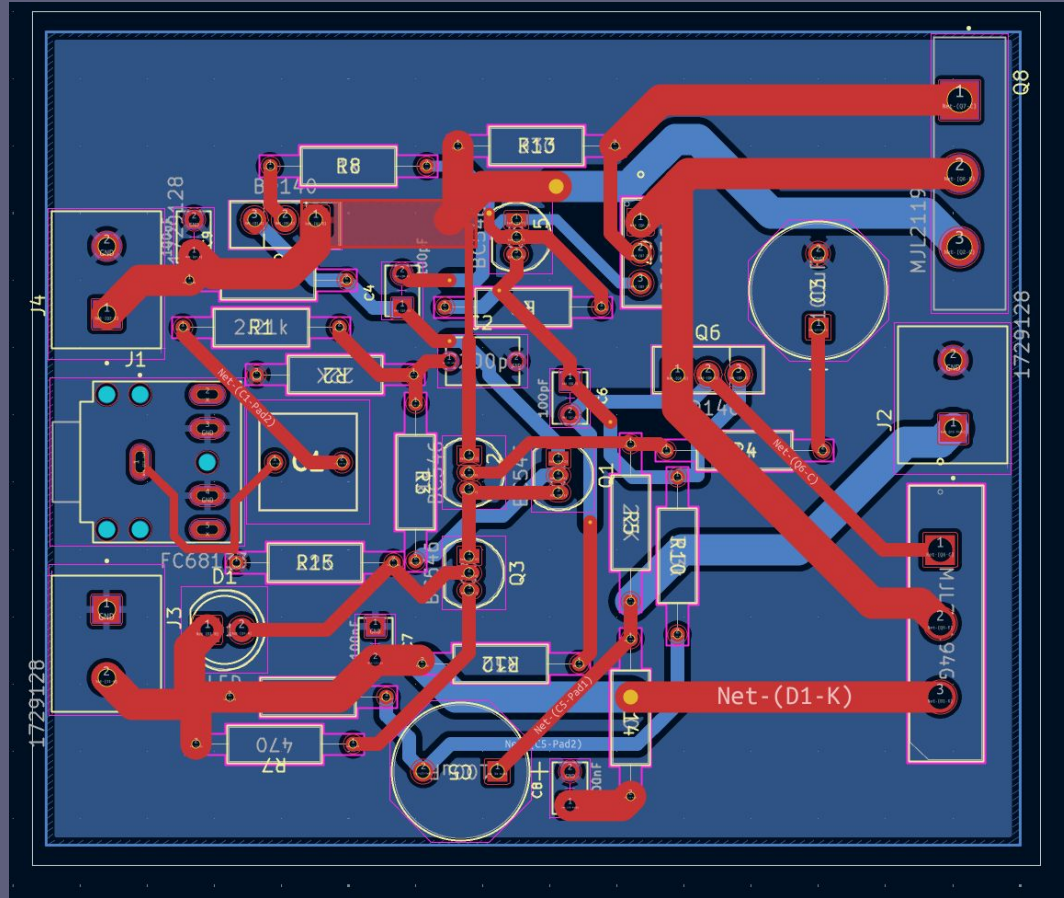
<https://www.youtube.com/watch?v=ZeihuCMit3U>



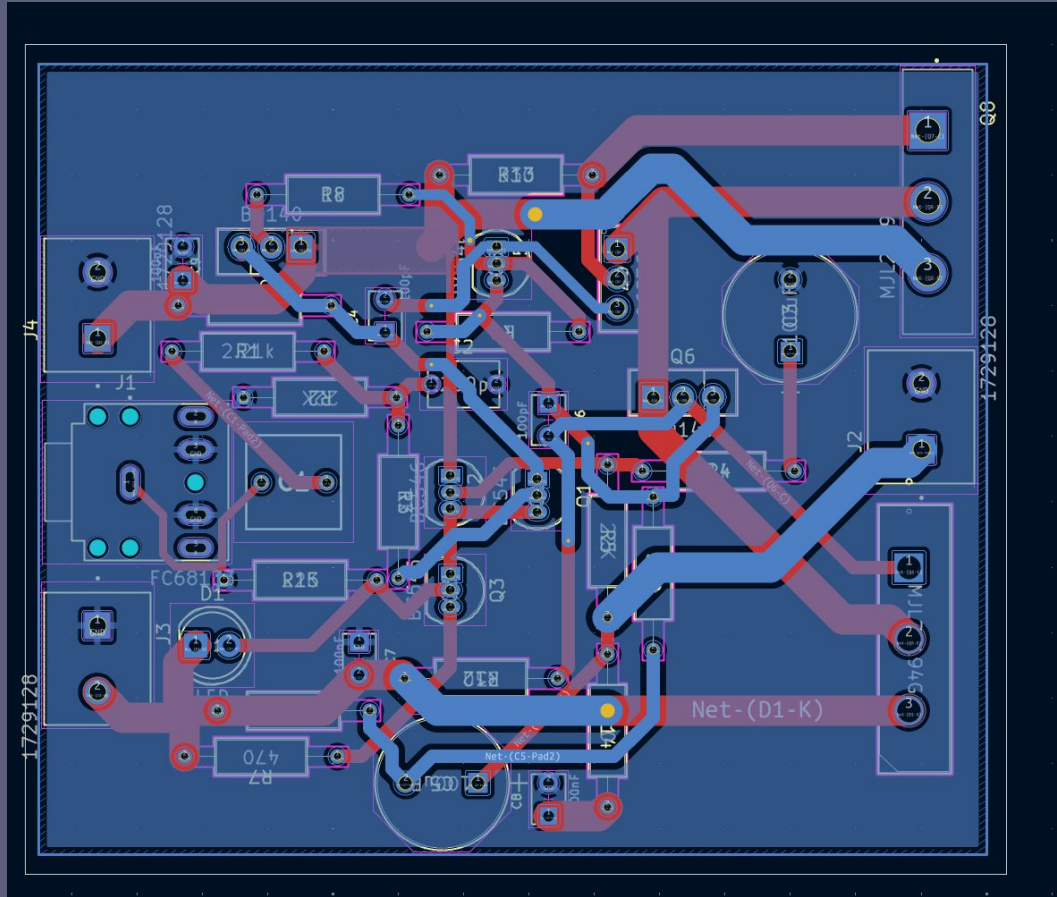
PCB Schematic



PCB - front layer



PCB - back layer



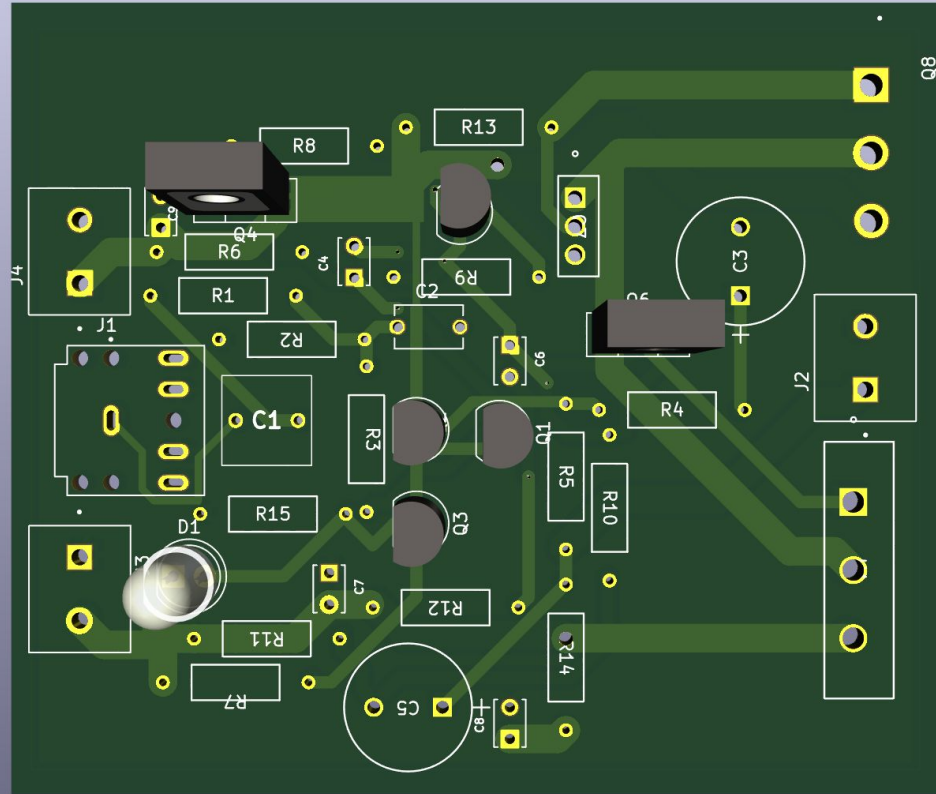
3D PCB

Software: KiCad 7.0

Layers: 2-layer board

Copper Weight: 1 oz
(35μm)

**Trace Width for Power
Rails:** 2.3 mm (Handles
>3A for output stage and
speaker drive)



Lessons Learned – ESP P3a Class AB Amplifier

1. PCB Layout is *Everything*

- High-current traces need to be treated like copper busbars — used **2.3 mm traces** for >3A paths (Q7/Q8 → Vout → Load)

2. Simulation vs. Reality

- Simulations in LTSpice showed ideal THD, slew rate, and stability
- Breadboard testing ($\pm 10\text{V}$ rails) revealed **subtle distortion** and thermal drift

3. Real analog design is about **debugging what simulation missed**

- Building first at **reduced voltage on breadboard** is underrated
- Every trace has a story — and analog layout is as much an art as a science

Cites

<https://sound-au.com/project3a.htm>